# **General Purpose Transistors**

# **PNP Silicon**

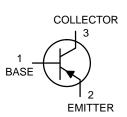
### **Features**

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



# ON Semiconductor®

# http://onsemi.com



# **MAXIMUM RATINGS** (T<sub>A</sub> = 25°C unless otherwise noted)

· · · · · · · · · · · · · · · · · · ·					
Rating	Symbol	Value	Unit		
Collector-Emitter Voltage	$V_{CEO}$		V		
BC856, SBC856		-65			
BC857, SBC857		-45			
BC858, NSVBC858, BC859		-30			
Collector-Base Voltage	$V_{CBO}$		V		
BC856, SBC856		-80			
BC857, SBC857		-50			
BC858, NSVBC858, BC859		-30			
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V		
Collector Current - Continuous	I <sub>C</sub>	-100	mAdc		
Collector Current - Peak	I <sub>C</sub>	-200	mAdc		

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



SOT-23 (TO-236AB) CASE 318 STYLE 6

### MARKING DIAGRAM



xx = Device Code

xx = (Refer to page 6)

M = Date Code\*= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		1			•
Collector – Emitter Breakdown Voltage BC856, SBC856 Series (I <sub>C</sub> = -10 mA) BC857, SBC857 Series BC858, NSBVC858 BC859 Series	V <sub>(BR)CEO</sub>	-65 -45 -30	- - -	- - -	V
	V <sub>(BR)CES</sub>	-80 -50 -30	- - -	- - -	V
Collector – Base Breakdown Voltage $(I_C = -10 \mu A)$ BC856, SBC856 Series BC857, SBC857 Series BC858, NSVBC858, BC859 Series	V <sub>(BR)</sub> CBO	-80 -50 -30	- - -	- - -	V
Emitter – Base Breakdown Voltage BC856, SBC856 Series $(I_E = -1.0 \ \mu\text{A})$ BC857, SBC857 Series BC858, NSVBC858, BC859 Series	$V_{(BR)EBO}$	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current ( $V_{CB} = -30 \text{ V}$ ) ( $V_{CB} = -30 \text{ V}$ , $T_A = 150^{\circ}\text{C}$ )	I <sub>CBO</sub>	- -	_ _	-15 -4.0	nA μA
ON CHARACTERISTICS					
DC Current Gain BC856A, SBC856A, BC857A, SBC857A, BC858A $(I_C = -10 \mu A, V_{CE} = -5.0 \text{ V})$ BC856B, SBC856B, BC857B, SBC857B, BC858B, NSVBC858B	h <sub>FE</sub>		90 150		-
BC857C, SBC857C BC858C		-	270	-	
$(I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ BC856A, SBC856A, BC857A, SBC857A, BC858A		125	180	250	
BC856B, SBC856B, BC857B, SBC857B, BC858B, NSVBC858B, BC859B BC857C, SBC857C, BC858C, BC859C		220 420	290 520	475 800	
Collector – Emitter Saturation Voltage ( $I_C = -10$ mA, $I_B = -0.5$ mA) ( $I_C = -100$ mA, $I_B = -5.0$ mA)	V <sub>CE(sat)</sub>	- -	_ _	-0.3 -0.65	V
Base – Emitter Saturation Voltage ( $I_C = -10$ mA, $I_B = -0.5$ mA) ( $I_C = -100$ mA, $I_B = -5.0$ mA)	V <sub>BE(sat)</sub>	_ _	-0.7 -0.9	_ _	V
Base – Emitter On Voltage ( $I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V}$ ) ( $I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V}$ )	V <sub>BE(on)</sub>	-0.6 -	- -	-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product $(I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ MHz})$	f⊤	100	_	_	MHz
Output Capacitance (V <sub>CB</sub> = -10 V, f = 1.0 MHz)	C <sub>ob</sub>	_	_	4.5	pF
Noise Figure ( $I_C = -0.2$ mA, $V_{CE} = -5.0$ Vdc, $R_S = 2.0$ k $\Omega$ , $f = 1.0$ kHz, BW = 200 Hz) BC856, SBC856, BC857, SBC857, BC858, NSVBC858 Series BC859 Series	NF	- -	- -	10 4.0	dB

### BC857/BC858/BC859/SBC857/NSVBC858

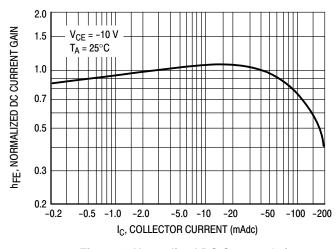


Figure 1. Normalized DC Current Gain

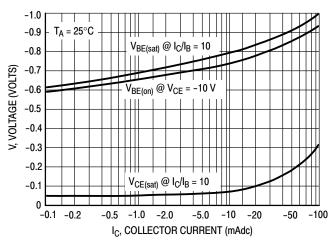


Figure 2. "Saturation" and "On" Voltages

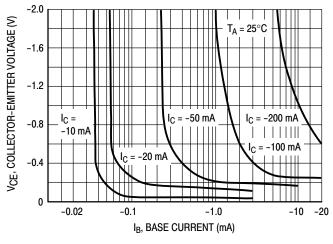


Figure 3. Collector Saturation Region

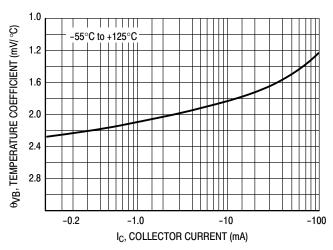


Figure 4. Base-Emitter Temperature Coefficient

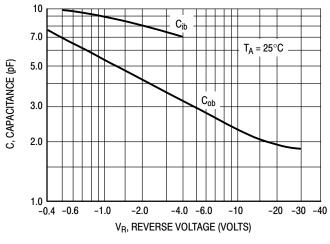


Figure 5. Capacitances

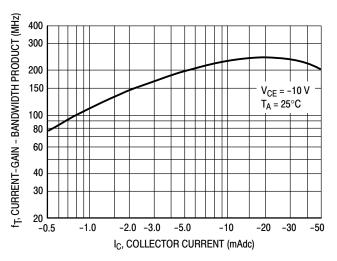


Figure 6. Current-Gain - Bandwidth Product

# BC856/SBC856

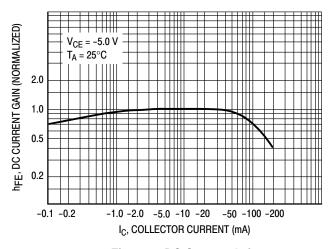


Figure 7. DC Current Gain

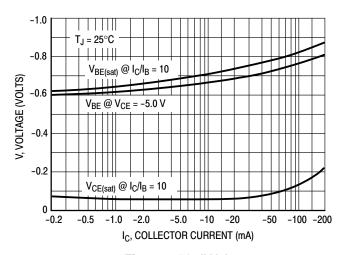


Figure 8. "On" Voltage

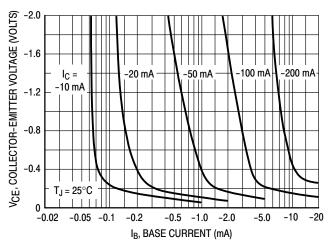


Figure 9. Collector Saturation Region

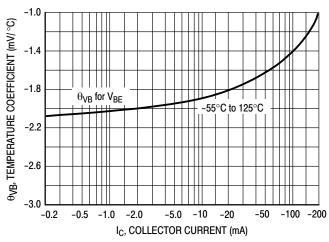


Figure 10. Base-Emitter Temperature Coefficient

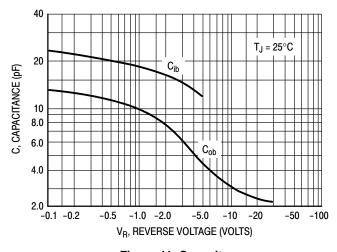


Figure 11. Capacitance

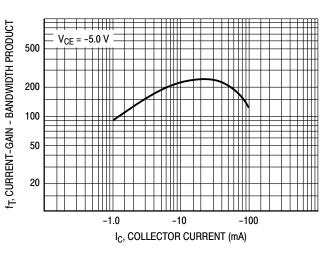


Figure 12. Current-Gain - Bandwidth Product

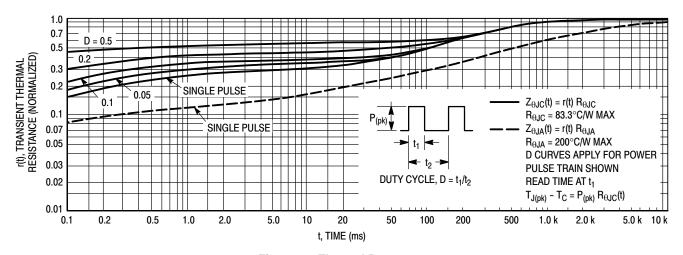


Figure 13. Thermal Response

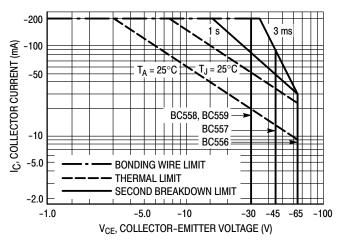


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate  $I_C$ – $V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon  $T_{J(pk)} = 150^{\circ}C$ ;  $T_{C}$  or  $T_{A}$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^{\circ}C$ .  $T_{J(pk)}$  may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

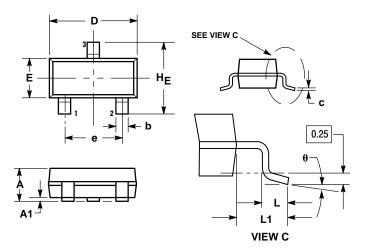
# **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
BC856ALT1G		SOT-23	0.000 / Town 0. Dool
SBC856ALT1G	3A	(Pb-Free)	3,000 / Tape & Reel
BC856ALT3G			10,000 / Tape & Reel
BC856BLT1G		SOT-23	0.000 / Town 0. Dool
SBC856BLT1G		(Pb-Free)	3,000 / Tape & Reel
BC856BLT3G	3B		40.000 /T 0.D 1
SBC856BLT3G			10,000 / Tape & Reel
BC857ALT1G	0.5	SOT-23	0.000 (T
SBC857ALT1G	3E	(Pb-Free)	3,000 / Tape & Reel
BC857BLT1G		SOT-23	0.000 / Town 0. Dool
SBC857BLT1G	3F	(Pb-Free)	3,000 / Tape & Reel
BC857BLT3G			10,000 / Tape & Reel
BC857CLT1G		SOT-23	0.000 / Town 0. Dool
SBC857CLT1G	3G (Pb-Free)	(Pb-Free)	3,000 / Tape & Reel
BC857CLT3G			10,000 / Tape & Reel
BC858ALT1G	3J	SOT-23 (Pb-Free)	
BC858BLT1G	-14	SOT-23	3,000 / Tape & Reel
NSVBC858BLT1G	3K	(Pb-Free)	
BC858BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC858CLT1G	3L	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC858CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC859BLT1G	_	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC859BLT3G	4B	SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC859CLT1G		SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC859CLT3G	4C	SOT-23 (Pb-Free)	10,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# PACKAGE DIMENSIONS

# SOT-23 (TO-236) CASE 318-08 ISSUE AP



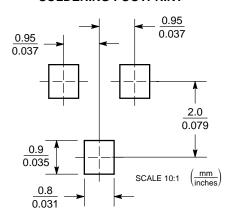
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 6: BASE

EMITTER COLLECTOR

### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent–Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary indifferent applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

# **PUBLICATION ORDERING INFORMATION**

# LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

**Phone**: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative